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In Situ Growth of Burl-like Nickel Cobalt Sulfide on Carbon Fiber as High-Performance Supercapacitors

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Nickel cobalt sulfide (NiCo_2S_4), a recently reported novel electrode material, has a higher electric conductivity than that of the NiCo_2O_4 . We describe a facile one-step route to the development of burl-like NiCo_2S_4 on carbon fiber paper/cloth (CFP/CFC) used as electrodes for supercapacitor. The influence of the carbon substrate on the crystal structure and electrochemical performance of the NiCo_2S_4 electrodes is evaluated. We obtain pure phase of NiCo_2S_4 over CFP substrate, whereas, mixed phase over CFC substrate. Superior pseudocapacitive performance is achieved over NiCo_2S_4 /CFP with large specific capacitance of 0.83 F cm^{-2} at a high current density of 25 mA cm^{-2} . The capacitance loss is 24.1 % after 5000 cycles at a current density of 20 mA cm^{-2} , displaying good cycle ability and high rate capability.

1 Introduction

Supercapacitors have attracted great interest in the past years because of their prominent properties like high power density, long cycle life, and short charging time¹⁻³. Among the factors that affect the performance of supercapacitor, the electrode material is one of the important factors in terms of its morphology, size, dimension, composition and so on. Therefore, various materials like traditional metal oxide, carbon materials, conductive polymer⁴ and recently developed metal chalcogenides (CoS , NiS_2 , VS_2 , GeSe_2 , etc)⁵⁻⁷ have been explored extensively aiming to find the ideal candidate with excellent performance and low cost. Thanks to the pioneering work of Prof. Hu and his group in 2010⁸, considerable efforts have been devoted to Nickel cobaltite (NiCo_2O_4) prepared by different methods with diverse morphologies. The NiCo_2O_4 electrode material is reported to exhibit good electrochemical performance, high electrical conductivity and potential industrialized application^{4, 9, 10}.

The pace of pursuing excellent electrode material can never stop. We all know that the elements of S and O belong to the same group in the Periodic Table of the Elements, thus the two elements have similar properties. Since NiCo_2O_4 has distinguished electrochemical properties, if the element of O is substituted by the element S, then the NiCo_2S_4 should also possess similar electrochemical performance. In fact, some binary metal sulfides such as Co sulfide (CoS , CoS_2 , Co_9S_8) and Ni sulfide (NiS , Ni_3S_2) have been proposed for a new type of electrode materials¹¹⁻¹⁷. Therefore, ternary metal sulfide could have potential application as electrode materials for supercapacitors.

Since 2013, Nickel cobalt sulfide (NiCo_2S_4), a new kind of electrode material candidate, has come into being in the region of

electrochemical capacitors. Herein, we listed the reported works on NiCo_2S_4 in Table 1 as far as we can find. NiCo_2S_4 is build around a closely packed array of S^{2-} ions, with Ni^{2+} and Co^{3+} cations occupying the tetrahedral and octahedral sites, respectively¹⁸. Compared to the NiCo_2O_4 material, NiCo_2S_4 is reported to have an electric conductivity ~100 times higher than that of NiCo_2O_4 ^{19, 20}. Furthermore, NiCo_2S_4 with a normal spinel crystal structure possesses more octahedral catalytic active sites of Co^{3+} cations compared to its counterpart with an inverse spinel structure¹⁸. Compared with binary metal sulfides, NiCo_2S_4 can offer richer redox reactions owing to the existence of Co and Ni ions^{19, 21}. Based on the above analyses and the practice listed in Table 1, we clear see that the NiCo_2S_4 is indeed a kind of outstanding electrode material for supercapacitors.

Table 1 Morphology, synthetic method and specific capacitance of NiCo₂S₄ electrode materials

Morphology	Raw materials	Current collector	Specific capacitance	Load mass	Ref
Urchin	CoCl ₂ , NiCl ₂ , Na ₂ S	-	1065 F g ⁻¹ (3 A g ⁻¹)	unknown	20
Nano Sheet/RGO	Co(NO ₃) ₂ , Ni(NO ₃) ₂ thiourea	-	1161 F g ⁻¹ (5 A g ⁻¹)	unknown	21
Flower, Tube, Cubic, Urchin	CoCl ₂ , NiCl ₂ , Na ₂ S	-	Tube-1048 F g ⁻¹ (3 A g ⁻¹)	4	22
Nanoplate	CoCl ₂ , Ni(Ac) ₂ , Na ₂ S	-	437 F g ⁻¹ (1 A g ⁻¹)	2.4	23
Nanoparticle/GO	CoCl ₂ , Ni(Ac) ₂ , S	-	755 F g ⁻¹ (4 A g ⁻¹)	5	24
Nanoparticle	CoCl ₂ , Ni(Ac) ₂ , S	-	770 F g ⁻¹ (4 A g ⁻¹)	5	25
Hollow nanoprism	Co(Ac) ₂ , Ni(Ac) ₂ , thioacetamide	-	895 F g ⁻¹ (1 A g ⁻¹)	1	26
Nano-Aggregates	Co(NO ₃) ₂ , NiSO ₄ , Na ₂ S	-	592 F g ⁻¹ (0.5 A g ⁻¹)	2.5-3.5	27
Nanotube	CoCl ₂ , NiCl ₂ , Na ₂ S	-	933 F g ⁻¹ (1 A g ⁻¹)	4-6	28
Nanotube	CoCl ₂ , NiCl ₂ , Na ₂ S	Ni foam	738 F g ⁻¹ (4 A g ⁻¹)	4.2	29
Nanotube	CoCl ₂ , NiCl ₂ , Na ₂ S	Ni foam	14.39 F cm ⁻² (5 mA cm ⁻²)	6	30
Nanowire	Co(NO ₃) ₂ , Ni(NO ₃) ₂ , Na ₂ S	Ni foam	2415 F g ⁻¹ , 6.0 F cm ⁻² (2.5 mA cm ⁻²)	2.5	31
Nanosheet	Co(Ac) ₂ , thioacetamide	Ni foam	5.71 F cm ⁻² (20 mA cm ⁻²)	2.1	32
Nanotube	CoCl ₂ , NiCl ₂ , H ₂ S	Carbon fiber paper	2.86 F cm ⁻² (4 mA cm ⁻²) 0.58 F cm ⁻² (20 mA cm ⁻²)	4.3	19
Nanosheet*	CoCl ₂ , NiCl ₂ , thiourea	Carbon cloth	1418 F g ⁻¹ (5 A g ⁻¹)	0.8	33

Note: * the material in ref [24], [25] and [33] is CoNi₂S₄ instead of NiCo₂S₄, we list herein because they are similar material.

Although NiCo₂S₄ is gaining the attention of researchers, however, from Table 1, we can see that the obtained results are still limit. First of all, most of the reported were NiCo₂S₄ powder instead of integrated electrode¹⁷⁻²⁵. The electrodes fabricated by the traditional slurry-coating technique have two disadvantages: one is that the increased "dead surface" leading to the limit of capacitive performance; and the other is that the used binder can decrease the electrical conductivity³⁴. Secondly, for the integrated electrodes, the current collector was mainly Ni foam, whereas low-cost carbon materials were rare. Carbon materials usually have large surface area, high porosity and good electric conductivity, and are considered as the backbone for conformal coating of transition metal oxides for supercapacitors³⁵, thus it is interesting to apply carbon fiber materials as current collector. Thirdly, most of the NiCo₂S₄ were prepared by a two-step procedure, which make it complicated and time-consuming to precisely control of the materials. Last, the reported morphology for NiCo₂S₄ integrated electrodes were mainly nanotube, nanowire and nanosheet. Because the morphology of material has a substantial influence on the speed of ion transfer and the capacity of charge storage⁴, it is desirable to synthesize materials with novel shape.

In order to further exploit the potential of NiCo₂S₄ based electrode materials, herein, we proposed a simple one-step

solvothermal strategy for the growth of burl-like NiCo₂S₄ on two kinds of commercial carbon fiber: carbon fiber paper (CFP) and carbon fiber cloth (CFC). Remarkably, the prepared NiCo₂S₄ architectures, especially loaded on CFP, manifests a specific capacitance of 0.83 F cm⁻² at a high current density of 25 mA cm⁻² and outstanding cycling stability at high rates. The capacitance of the NiCo₂S₄/CFP remained as high as 82.8 % after 5000 cycles at a current density of 20 mA cm⁻².

2 Experimental

2.1 Materials and methods

Synthesis of NiCo₂S₄ supported on CFP/CFC: All the chemicals were of analytical grade. Commercial CFP or CFC (approximately 1 cm × 4 cm, Shanghai hesen Electronic Co. Ltd.; CFP, Spec: HCP030, 0.30 mm in depth, resistivity: 3 mΩ cm²; CFC, Spec: HCP331, 0.30 mm in depth, resistivity: 3.14 mΩ cm², longitudinal resistance, <0.1×10⁻²Ω) were purified under ultrasonic for 15 min in 5M HCl aqueous solution, absolute ethanol and deionized water, respectively. 0.5 mmol of Co(NO₃)₂·6H₂O, 0.25 mmol of Ni(NO₃)₂·6H₂O, 3 mmol of thioacetamide (TAA) were dissolved into 12 mL of absolute methanol, and then transferred into a 25 mL Teflon-lined stainless steel autoclave. A piece of the pre-treated CFP or CPC was put vertically in the autoclave, heated to 120 °C for 5 h. After the solvothermal process, the products were ultrasonically cleaned with DI water and ethanol, and dried at 60 °C.

2.2 Materials Characterization

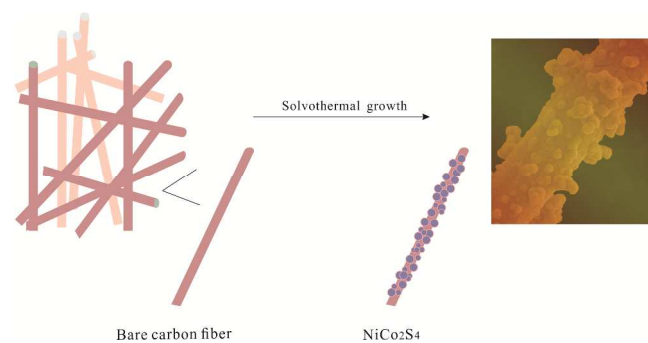
The crystal phase of the products was examined by X-ray diffraction diffractometer (XRD, Bruker, D8, Cu Kα, λ=1.5406 Å). The samples were scraped from the carbon fiber carefully for the XRD test. The morphology was characterized by scanning electron microscopy (SEM, Hitachi, S-3400N) and transmission electron microscopy (TEM, Shimadzu, EPMA-1600) equipped with an energy dispersive X-ray spectrometer (EDS). X-ray photoelectron spectroscopy (XPS) was performed on a Thermo ESCALAB 250 instrument equipped with a monochromatic Al Kα (1486.6 eV) X-ray source. The spectra are calibrated using the carbon peak

2.3 Electrochemical Measurements

The cyclic voltammetry (CV) curves and galvanostatic charge-discharge were measured on Autolab PGSTAT302N Electrochemical Workstation in a three-electrode cell containing 2 M KOH aqueous solution as electrolyte at room temperature. The carbon fiber supported electroactive materials (~1 cm² in area, loading mass of NiCo₂S₄ is ca.2.3 mg) serves directly as the working electrode. The counter electrode and the reference electrode were a platinum foil electrode and a saturated calomel electrode (SCE), respectively. The electrochemical impedance spectroscopy (EIS) was tested in a frequency range from 100 kHz to 0.01 Hz at open circuit potential. Areal capacitances are calculated using the equations, $C_s = \frac{I\Delta t}{S\Delta V}$, where C_s (F cm⁻²) is areal capacitance, I (A) represented discharge current, S (cm²), ΔV (V), and Δt (s) designate the area of the electrode, potential drop during discharge, and total discharge time, respectively.

3. Results and discussion

3.1 Synthesis and characterization



Scheme.1 Schematic illustration of synthetic NiCo₂S₄ on CFP/CFC

The synthetic strategy for NiCo₂S₄ supported on CFP/CFC is shown in Scheme.1. TAA is used as the sulfur source, it can release sulfide ions in aqueous medium²⁶. Burl-like NiCo₂S₄ were obtained through the reaction among Co²⁺, Ni²⁺, and TAA under solvothermal condition, and many metal sulfides such as MnS, NiS, Ni₃S₄, and NiCo₂S₄ have been prepared by similar strategy using TAA as sulfur source³⁶⁻³⁸. Unlike the anion-exchange reaction mechanism widely existed in two-step reaction for synthesis of NiCo₂S₄^{22, 26, 30, 31}, we think that the formation of NiCo₂S₄ in our case is through the coprecipitation process as Shimizu et al³⁷ suggested.

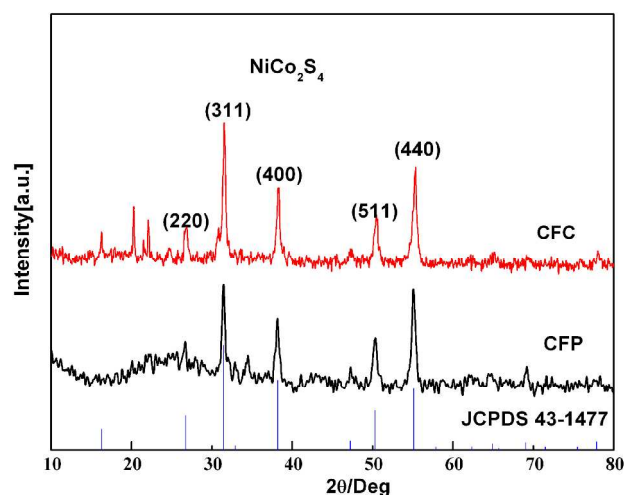


Fig.1 XRD patterns of NiCo₂S₄ supported on CFP and CFC

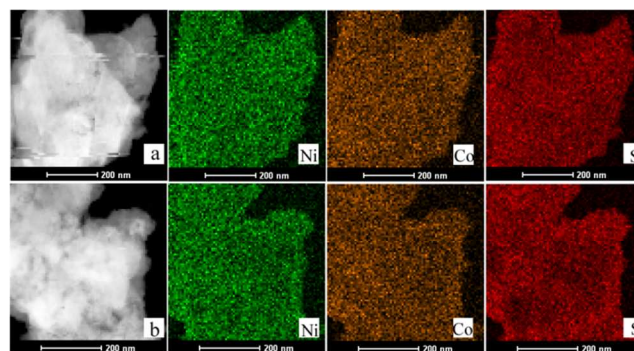


Fig.2 EDX mapping results of (a) NiCo₂S₄/CFP and (b) NiCo₂S₄/CFC

To prove that we have successfully obtained NiCo₂S₄, XRD, EDX mapping and XPS characterizations were carried out. Fig. 1 shows the XRD patterns of the NiCo₂S₄ samples loaded on CFP and CFC substrate. For the two samples, they both show diffraction peaks at 26.8 °, 31.5 °, 38.1 °, 50.4 ° and 55.2 ° corresponding to the respective (220), (311), (400), (511) and (440) planes of the cubic type NiCo₂S₄ (JCPDS# 43-1477). However, for the CFC loaded sample, there are two extra peaks located at around 20 ° and 22 °. These impurity peaks can be assigned to the S (JCPDS#24-1251) formed by the decomposition of TAA. To better understand the presence of impurity, we use SEM-EDX to examine the difference between CFP and CFC substrate. As shown in Supporting Information Fig.S(1-2), the CFP is mainly composed by C (~99 wt %) and O (~1 wt%). However, besides C and O element, the CFC contains other impurities such as Na (~0.1 wt%), Si (~0.1 wt%), and P(~0.3 wt%). Such unexpected impurities in CFC substrate might lead to the presence of S in NiCo₂S₄ under solvothermal conditions. The difference in the phase structure demonstrate that the substrate can not only influence the final morphology of active materials under solvothermal condition³⁹, but also can affect the purity of crystal phase. The mapping images (Fig.2) of Ni, Co, and S show uniform and continuous dispersion throughout the carbon fiber, indicating that homogeneous NiCo₂S₄ materials were covered on the carbon fiber substrate. The NiCo₂S₄ loaded on CFP and CFC show similar XPS spectra as displayed in Fig.3. As shown in Fig.3a, the energy difference between Ni 2p_{3/2} (853 eV) and Ni 2p_{1/2} (870 eV) indicate the existence of both divalent and trivalent states of Ni^{19, 23}. As regards for the Co 2p spectrum, two strong peaks at 779.0 eV for Co 2p_{3/2} and 794.0 eV for Co 2p_{1/2} can be found, suggesting the coexistence of Co (III) and Co (II)^{19, 23, 19, 23}. As for the S 2p spectrum, it can be divided into two main peaks located at around 162.0 and 163.2 eV and one shake-up satellite at about 169.0 eV. The component at 163.2 eV is characteristics of metal-sulphur bonds, while the peak at 162.0 can be assigned to the sulphur ion in low coordination on the surface²⁰.

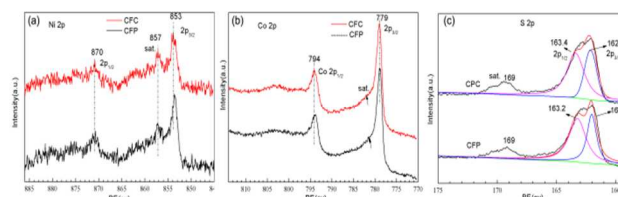


Fig.3 XPS spectra of (a) Co 2p, (b) Ni 2p, and (c) S 2p for the NiCo₂S₄.

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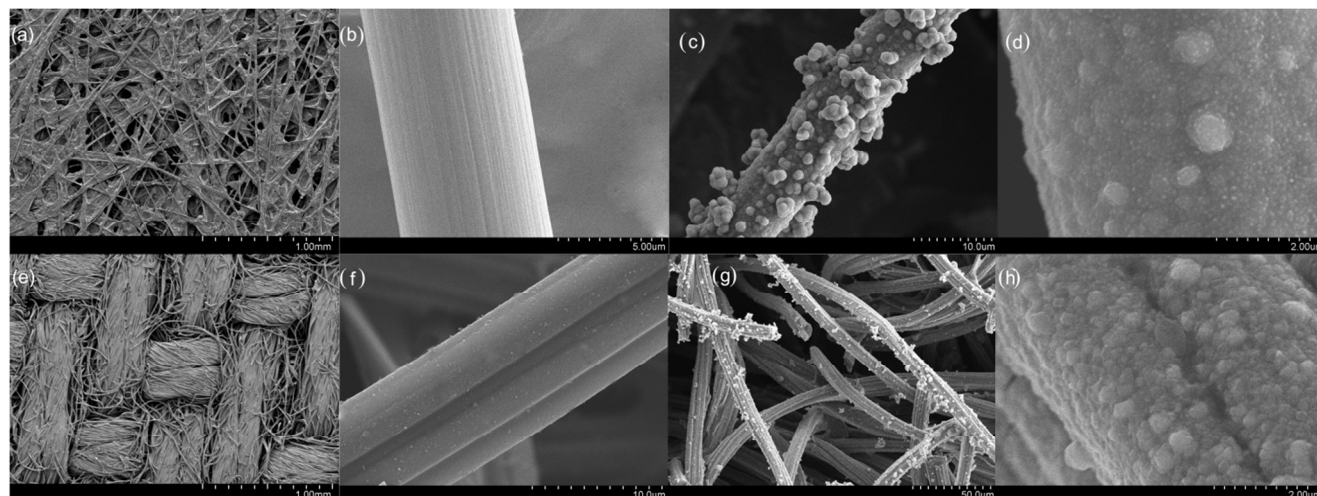


Fig.4 SEM images of (a-b) bare CFP, (c-d) NiCo₂S₄/CFP, (e-f) bare CFC, and (g-h) NiCo₂S₄/CFC

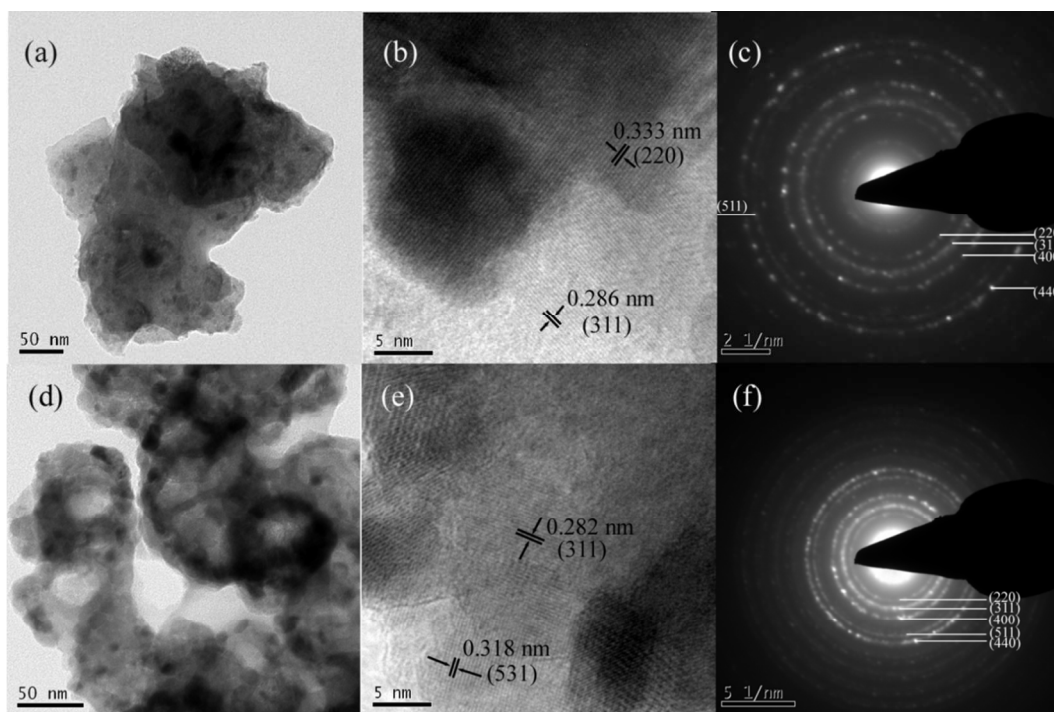


Fig. 5TEM, HRTEM images and SAED patterns of (a-c) NiCo₂S₄/CFP, and (d-f) NiCo₂S₄/CFC

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SEM and TEM tests provide further insights into the morphologies and detailed geometrical structures of the NiCo₂S₄ materials. The low magnification image of CFP is displayed in Fig.2(a), the carbon fiber interconnects with each other formed

web-like structure. If examine carefully, we can see that the carbon fiber in CFP has very smooth surface (Fig.2b). However, for the CFC, it shows the typical morphology of carbon cloth with crossed carbon fiber, and the surface of its carbon fiber is

dotted with tiny flakes (Fig.2(e-f)). After solvothermal process with the source chemicals, as shown in Fig.4 (c-d), a large quantity of burl-like NiCo₂S₄ have grown on the surface of the carbon fiber substrate. Similar phenomena can be observed over the CFC supported NiCo₂S₄ material (Fig. 4 (g-h)) and the surface of CFC has been dotted with NiCo₂S₄ humps. The TEM, HRTEM and corresponding SAED patterns of NiCo₂S₄ scraped down from CFP and CFC are displayed in Fig.5 (a-c) and Fig.5 (d-f), respectively. As for NiCo₂S₄ supported on CFP, we can see from Fig. 5a that the NiCo₂S₄ burls are actually composed of different size of nanoflakes. Based on the HRTEM image (Fig. 5b), the lattice spacing of 0.286 nm and 0.333 nm corresponds to the (311) and (220) crystal planes of NiCo₂S₄. The SAED pattern (Fig.5c) demonstrates a polycrystalline structure, and the diffraction rings can be indexed to the (220), (311), (400), (511) and (440) planes of NiCo₂S₄. As for NiCo₂S₄ supported on CFC, it is also constructed by small nanoflakes (Fig.5d). Meanwhile, its lattice fringes shown in Fig. 5e can be indexed to the (311) and (531) crystal planes of the NiCo₂S₄. The SAED pattern in Fig. 5f confirms the polycrystalline nature of the material.

3.2 Electrochemical characterization

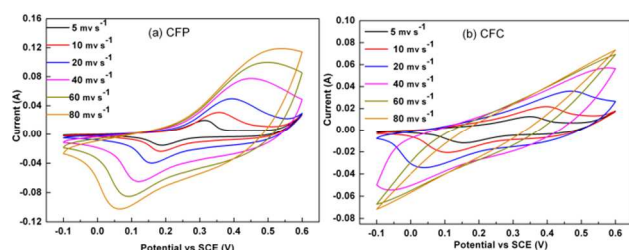
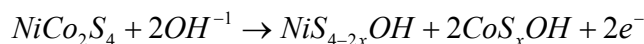


Fig.6 The CV curves of the (a) NiCo₂S₄/CFP electrode and (b) NiCo₂S₄/CFC electrode at different scan rates of 5, 10, 20, 40, 60 and 80 mV s⁻¹

The electrochemical properties of the prepared NiCo₂S₄ materials were investigated in the three-electrode measurements with 2 M KOH as the electrolyte. The cyclic voltammetry (CV) measurements under different scan rate are representing in Fig. 6. The cyclic voltammograms of NiCo₂S₄ grown over CFP substrate display a distinct pair of redox peaks during the positive and negative sweeps (Fig. 6a). The shape of the CV curves reveals the pseudocapacitive characteristics of the NiCo₂S₄ electrode, which agrees well with the previous reports^{24, 25, 32}. The redox peaks are caused by the reversible redox reaction of NiCo₂S₄ in alkaline electrolyte according to the following equation^{19, 30, 32}:



Compared with the CV curves of the NiCo₂S₄/CFP, as observed from Fig.5b, the NiCo₂S₄/CFC behaves a relatively less obvious pair of redox peaks. Especially, under high scan rate (>40 mV s⁻¹), the redox peaks almost disappear, and this indicates that the polarization of the NiCo₂S₄/CFC electrode is more serious than that of NiCo₂S₄/CFP.

To compare the influence of substrate on capacitance, the CV curves of NiCo₂S₄/CFP and NiCo₂S₄/CFC under the same scan rate of 20 mV s⁻¹ are shown in Supporting Information Fig. S2. From Fig.S 2, we can clear observe that the variation in redox peaks position for the two samples, and this phenomena is due to the difference in electrode polarization behaviours³². As the specific capacitance is proportional to the area of the CV curve, apparently, NiCo₂S₄/CFP shows bigger CV curve area than that of the NiCo₂S₄/CFC, indicating that NiCo₂S₄/CFP has higher capacitance and better electrochemical activity. Based on the CV analysis, CFP is more suitable to be used as current collector than CFC.

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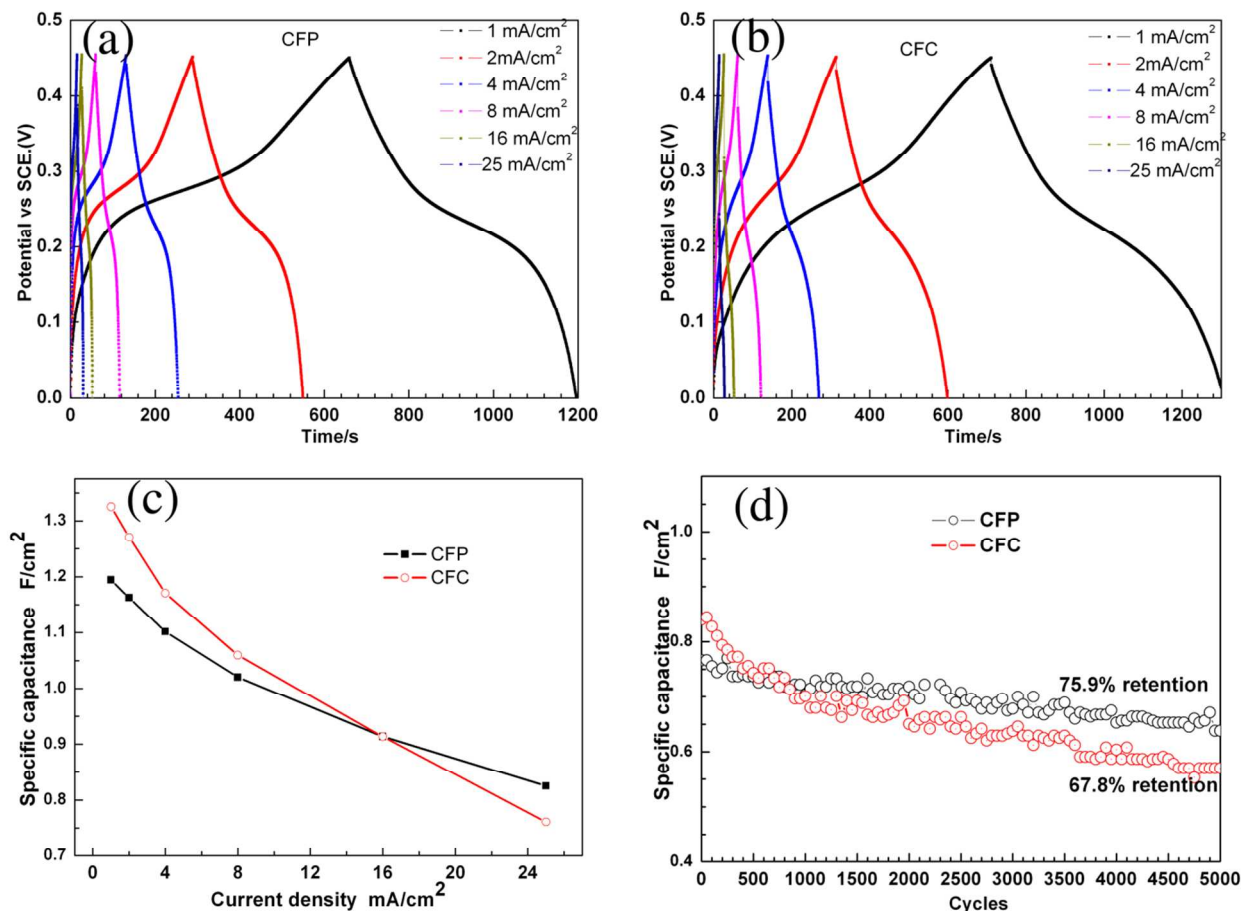


Fig.7 Galvanostatic current charge-discharge curves of (a) NiCo₂S₄/CFP electrode and (b) NiCo₂S₄/CFC electrode at different current density; (c) the specific capacitance as a function of current density of the NiCo₂S₄/CFP and NiCo₂S₄/CFC electrode; (d) the cycling performance at constant current density of 20 mA cm⁻² of the two electrodes.

To further evaluate the capacitive performance of the NiCo₂S₄/CFP and NiCo₂S₄/CFC electrodes, we carried out galvanostatic charge-discharge test, and the results are shown in Fig. 7(a-b). The comparison of galvanostatic charge-discharge curves for the two samples at a constant current density of 25 mA cm⁻² is given in Fig.S 3(Supporting Information). The plateaus in the charge/discharge curves imply the existence of Faradaic process which is related with the Ni ions and Co ions^{19, 30}, and this result is consistent with the CV analysis. Obviously, the charge-discharge curves of NiCo₂S₄/CFP are more symmetric at high current density (for example, 16 and 25 mA cm⁻²), implying that the NiCo₂S₄/CFP electrode has higher charge-discharge coulombic efficiency and lower polarization^{34, 40}. The specific capacitances of the two NiCo₂S₄ products are present in Fig.7c as a function of current density. Specifically, the specific capacitance

of the NiCo₂S₄/CFP is 1.19, 1.16, 1.10, 1.02, 0.91 and 0.83 F cm⁻² at the current density of 1, 2, 4, 8, 16 and 25 mA cm⁻², respectively. In contrast, under the same series of current density, the specific capacitance of the NiCo₂S₄/CFC is 1.33, 1.27, 1.17, 1.06, 0.91 and 0.76 F cm⁻². At lower current density, ions can penetrate into the inner-structure of electrode material and make full use of the active material, thus leading to a relatively higher specific capacitance. At higher current density, on the contrary, only the outer surface of electrodes can be effectively utilized, thus resulting in a relatively lower specific capacitance^{32, 41}. Therefore, with the current density rising, the specific capacitance is decreasing accordingly. Despite that our prepared NiCo₂S₄/CFP do not show excellent specific capacitance as the reported NiCo₂S₄³⁰⁻³², however, the NiCo₂S₄/CFP does exhibit superior specific capacitance than those NiCo₂S₄^{19, 23, 26} and better

electrochemical activity than NiCo₂O₄ supported on carbon fiber⁴²⁻⁴⁵. Furthermore, for NiCo₂S₄/CFP, there is around 70 % initial capacitance retention as the current density increases from 1 mA cm⁻² to 25 mA cm⁻², and the high-rate capability is better than that of NiCo₂S₄/CFC with only 57% initial capacitance retention. This relatively good rate capability is critical for its potential application.

The long-term stability was tested by galvanostatic charge-discharge cycling at a current density of 20 mA cm⁻² (Fig. 7d). For NiCo₂S₄/CFP electrode, the capacitance decreased slowly, and the total capacitance loss is 24.1 % after 5000 cycles. To the best of our knowledge, the cycling performance of the NiCo₂S₄/CFP electrode is worse than that of reported NiCo₂S₄^{19, 20, 30, 32}, but superior to those previously reported values²¹⁻²⁴. In comparison, the capacitance loss for NiCo₂S₄/CFC electrode is ~32.2 %. The charge-discharge efficiency, namely Coulombic efficiency, is estimated according to the following equation: $\eta = t_d / t_c \times 100\%$, where t_c and t_d are the charge and discharge intervals, respectively. The two electrode materials exhibited a higher charge-discharge efficiency of ~99% during the entire test. From the electrochemical characterization, the NiCo₂S₄/CFP electrode exhibits superior electrochemical performance with both higher capacitance and better cycling stability than that of NiCo₂S₄/CFC. Based on the structure and morphology characterization, we know that the two NiCo₂S₄ have similar morphology but different body composition. NiCo₂S₄ supported over CFC is not pure but with impurity, and this might be the main reason for such variation in electrochemical performance.

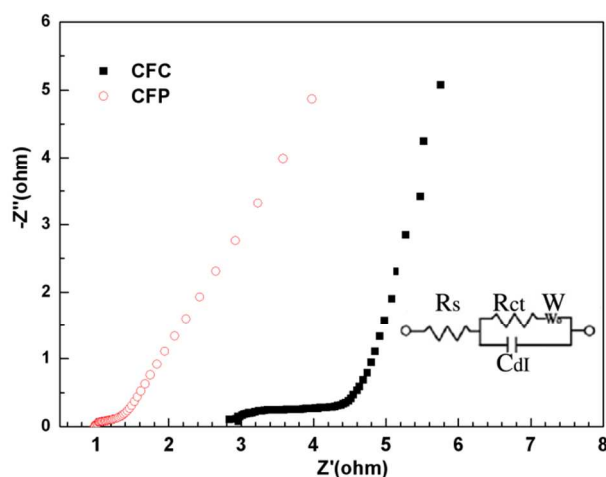


Fig.8 Nyquist plots of the EIS of the NiCo₂S₄/CFP and NiCo₂S₄/CFC electrode at bias potential of 0.35 V and the equivalent circuit diagram.

To gain further insight into the transport kinetics of the electrochemical behaviours, we resorted to electrochemical impedance spectroscopy (EIS) carried out at open circuit potential in the frequency range between 0.01 Hz and 100 kHz. Fig. 8 shows the EIS of the NiCo₂S₄/CFP and NiCo₂S₄/CFC electrodes and the equivalent circuit is present inset. Where, the equivalent circuit includes the following parameters: equivalent series resistance (R_s), charge-transfer resistance (R_{ct}), double-layer capacitance (C_{dl}), pseudocapitance (C_{ps}) and Warburg behaviour (W). The R_s for the NiCo₂S₄/CFP and is ca. 0.98 Ω ,

which is much smaller than that of NiCo₂S₄/CFC (2.83 Ω). The smaller R_s value of NiCo₂S₄/CFP indicates that the interfacial contact between NiCo₂S₄ deposits and carbon fiber paper are consistent. Furthermore, the NiCo₂S₄/CFP electrode displays even smaller diameter of the semicircle in the impedance spectrum than that of NiCo₂S₄/CFC electrode, and this indicates that NiCo₂S₄/CFP has relatively lower charge-transfer resistance. Such difference in EIS of the two samples might be caused by the impurity of the NiCo₂S₄/CFC. In general, the EIS results clearly demonstrate that the NiCo₂S₄/CFP exhibits favourable charge-transfer kinetics and fast electron transport compared to NiCo₂S₄/CFC, and thus further proving that NiCo₂S₄/CFP electrode has superior electrochemical performance compared to its counterpart.

Conclusions

In summary, we have prepared two kinds of NiCo₂S₄ electrodes supported on carbon fiber paper and carbon fiber cloth respectively using a facile one-step solvothermal method. Although they both belong to carbon fiber materials, however, the substrates do matter in terms of the supported NiCo₂S₄ purity and activity! The NiCo₂S₄/CFP exhibited favourable charge-transfer kinetics and fast electron transport compared to NiCo₂S₄/CFC, and thus showing superior electrochemical performance than its counterpart. The self-supported hybrid NiCo₂S₄/CFP electrode showed high specific capacitance of 1.19 and 0.83 F cm⁻² at current densities of 1 and 25 mA cm⁻², respectively, and exhibited desirable cycling stability as well as high rate capability. Considering the facile and cost-effective synthesis route and relatively high performance, the NiCo₂S₄/CFP might hold great promise as an active electrode for electrochemical supercapacitor.

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Notes and references

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table of contents entry

NiCo₂S₄/CFP displayed good cycle ability and high rate capability with capacitance loss of 24.1 % after 5000 cycles.

